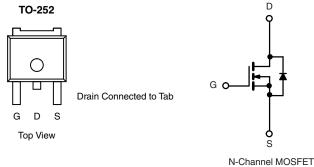


Vishay Siliconix

Automotive N-Channel 150 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY				
150				
0.052				
25				
Single				



FEATURES

- TrenchFET[®] Power MOSFET
- Package with Low Thermal Resistance
- 100 % R_g and UIS Tested
- AEC-Q101 Qualified
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>



ORDERING INFORMATION				
Package	TO-252			
Lead (Pb)-free and Halogen-free	SQD25N15-52-GE3			

ABSOLUTE MAXIMUM RATINGS	(T _C = 25 °C, unless	s otherwise noted	i)		
PARAMETER	SYMBOL	LIMIT	UNIT		
Drain-Source Voltage	V _{DS}	150	V		
Gate-Source Voltage	V _{GS}	± 20	v		
Continuous Drain Current	T _C = 25 °C	I	25	A	
Continuous Drain Current	T _C = 125 °C	I _D	16		
Continuous Source Current (Diode Conduction)	a	I _S	50		
Pulsed Drain Current ^b		I _{DM}	63		
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	30		
Single Pulse Avalanche Energy	L = 0.1 MH	E _{AS}	45	mJ	
Maximum Power Dissipation ^b	T _C = 25 °C	D	107	w	
	T _C = 125 °C	P _D	35	vv	
Operating Junction and Storage Temperature F	Range	T _J , T _{stg}	- 55 to + 175	°C	

THERMAL RESISTANCE RATINGS						
PARAMETER		SYMBOL	LIMIT	UNIT		
Junction-to-Ambient	PCB Mount ^c	R _{thJA}	50	°C/W		
Junction-to-Case (Drain)		R _{thJC}	1.4	C/W		

Notes

c. When mounted on 1" square PCB (FR-4 material).

a. Package limited.

b. Pulse test; pulse width $\leq 300~\mu\text{s},~\text{duty}~\text{cycle} \leq 2~\%.$

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SQD25N15-52

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNI
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS}=0~V,~I_D=250~\mu A$		150	-	-	v
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$		2.5	3	4	v
Gate-Source Leakage	I _{GSS}	V _{DS} =	$V_{DS} = 0 V, V_{GS} = \pm 20 V$		-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = 150 V	-	-	1	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$	$V_{DS} = 150 \text{ V}, \text{ T}_{\text{J}} = 125 ^{\circ}\text{C}$	-	-	50	μA
		$V_{GS} = 0 V$	V _{DS} = 150 V, T _J = 175 °C	-	-	250	
On-State Drain Current ^a	I _{D(on)}	$V_{GS} = 10 V$	$V_{DS} \ge 5 V$	30	-	-	A
		$V_{GS} = 10 V$	I _D = 15 A	-	0.038	0.052	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 10 V$	I _D = 15 A, T _J = 125 °C	-	-	0.104	Ω
		$V_{GS} = 10 \text{ V}$	I _D = 15 A, T _J = 175 °C	-	-	0.136	1
Forward Transconductanceb	9 _{fs}	V _{DS}	= 15 V, I _D = 15 A	-	33	-	S
Dynamic ^b		·					
Input Capacitance	C _{iss}			-	1760	2200	pF
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = 25 V, f = 1 MHz	-	215	270	
Reverse Transfer Capacitance	C _{rss}			-	80	100	
Total Gate Charge ^c	Qg			-	34	51	nC
Gate-Source Charge ^c	Q _{gs}	$V_{GS} = 10 V$	$V_{DS} = 75 \text{ V}, \text{ I}_{D} = 25 \text{ A}$	-	14.5	-	
Gate-Drain Charge ^c	Q _{gd}			-	5.4	-	
Gate Resistance	Rg		f = 1 MHz		1.8	2.6	Ω
Turn-On Delay Time ^c	t _{d(on)}			-	11	17	
Rise Time ^c	t _r	V _{DD}	= 75 V, R_L = 3 Ω	-	11	17	ns
Turn-Off Delay Time ^c	t _{d(off)}		$V_{GEN} = 10 \text{ V}, \text{ R}_{g} = 1 \Omega$	-	20	30	
Fall Time ^c	t _f	7	1 1		6	9	1
Source-Drain Diode Ratings and Char	acteristics ^b	·					
Pulsed Current ^a	I _{SM}			-	-	63	A
Forward Voltage	V _{SD}	I _F = 20 A, V _{GS} = 0 V		-	0.87	1.5	V
lotes . Pulse test; pulse width \leq 300 µs, duty c . Guaranteed by design, not subject to p	ycle ≤ 2 %.	1		1	0.01	1.0	<u>I</u>

c. Independent of operating temperature.

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SPECIFICATIONS (T_C = 25 °C, unless otherwise noted)

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



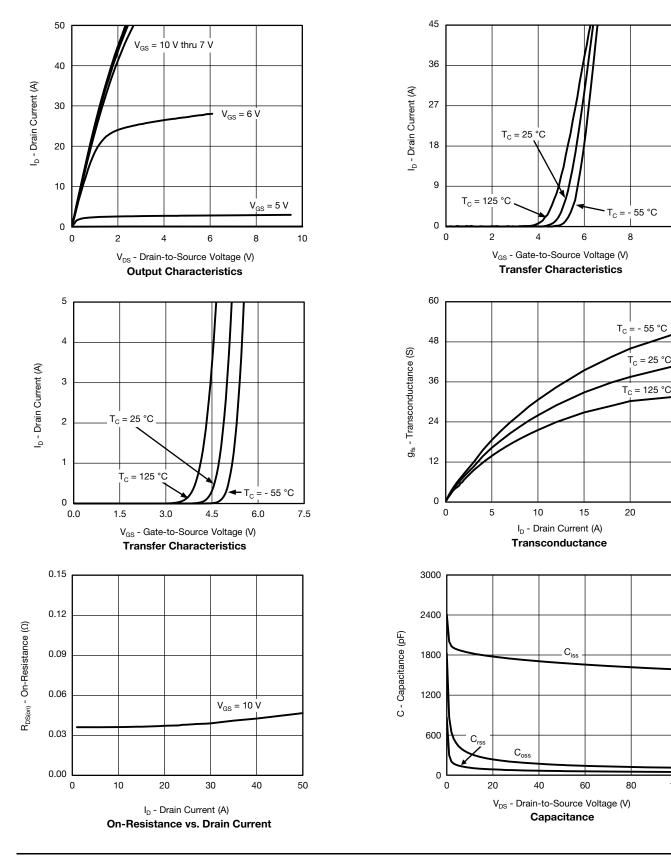
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10

25

100

TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



S12-2006-Rev. F, 20-Aug-12

3

Document Number: 68604

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75 100 125

T_J = 25 °C

6



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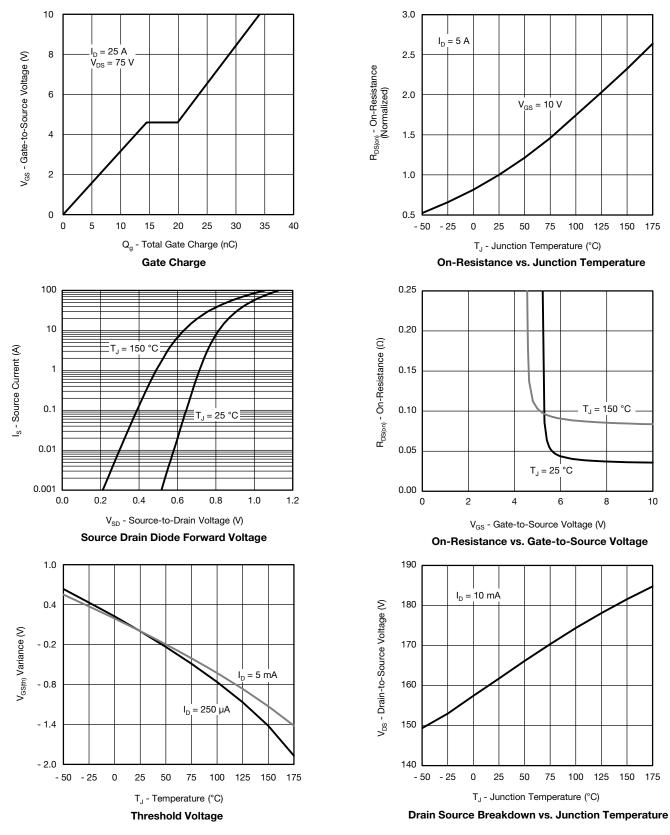
150 175

T_J = 150 °C

8

10

TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



Document Number: 68604

75 100 125 150 175

S12-2006-Rev. F, 20-Aug-12

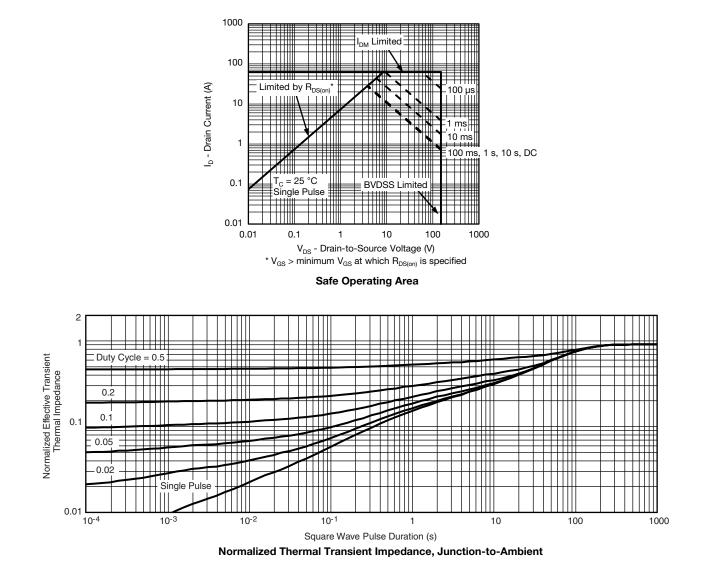
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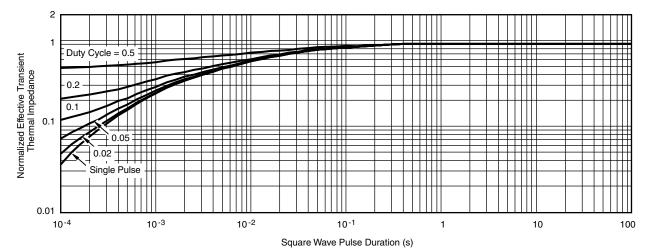
THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)





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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

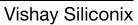
- Normalized Transient Thermal Impedance Junction-to- Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?68604.

The characteristics shown in the two graphs





Е b3 Ľ Δ ŝ b2 e1 Б E1

C2 т gage plane height (0.5 mm)

-C

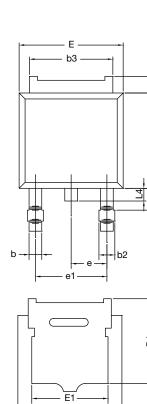
- A1

TO-252AA Case Outline

	MILLIN	IETERS	INC	HES	
DIM.	MIN.	MAX.	MIN.	MAX.	
А	2.18	2.38	0.086	0.094	
A1	-	0.127	-	0.005	
b	0.64	0.88	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	
С	0.46	0.61	0.018	0.024	
C2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	
D1	4.10	-	0.161	-	
Е	6.35	6.73	0.250	0.265	
E1	4.32	-	0.170	-	
Н	9.40	10.41	0.370	0.410	
е	2.28	BSC	0.090 BSC 0.180 BSC		
e1	4.56	BSC			
L	1.40	1.78	0.055	0.070	
L3	0.89	1.27	0.035	0.050	
L4	-	1.02	-	0.040	
L5	1.01	1.52	0.040	0.060	
ECN: T13-0592-Rev. A, 02-Sep-13 DWG: 6019					

Note

• Dimension L3 is for reference only.





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RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)

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